# SUN076512

New Generation N-Ch Power MOSFET

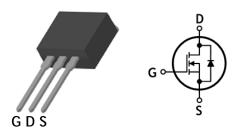
### HIGH SPEED SWITCHING APPLICATION

#### **Features**

- Low drain-source On resistance:  $R_{DS(on)}=1.1\Omega$  (Typ.)
- Low gate charge: Q<sub>g</sub>=18nC (Typ.)
- Low reverse transfer capacitance: C<sub>rss</sub>=5.5pF (Typ.)
- RoHS compliant device
- 100% avalanche tested

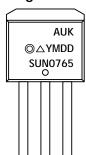
#### **Ordering Information**

Part Number	Marking	Package
SUN0765I2	SUN0765	I2-PAK



12-PAK

#### **Marking Information**



Column 1: Manufacturer

Column 2: Production Information

e.g.) ⊚△YMDD

-. O: Option Code (H: Halogen Free)

-. △: Factory Management Code

-. YMDD: Date Code (Year, Month, Date)

Column 3: Device Code

Absolute maximum ratings (T<sub>C</sub>=25°C unless otherwise noted)

Characteristic	Symbol		Rating	Unit				
Drain-source voltage	V <sub>DSS</sub>		V <sub>DSS</sub>		650	V		
Gate-source voltage	$V_{GSS}$		$V_{GSS}$		$V_{GSS}$		±30	V
Drain current (DC)	I <sub>D</sub>	T <sub>c</sub> =25°C	7	А				
brain current (bc)		T <sub>c</sub> =100°C	4.43	А				
Drain current (Pulsed) *		I <sub>DM</sub>	28	А				
Single avalanche energy (Note 2)		E <sub>AS</sub>	92.9	mJ				
Repetitive avalanche current (Note 1)		I <sub>AR</sub>	7	А				
Repetitive avalanche energy (Note 1)		E <sub>AR</sub>	11	mJ				
Power dissipation		P <sub>D</sub>	110	W				
Junction temperature		TJ	150	°C				
Storage temperature range		$T_{stg}$	-55~150	°C				

<sup>\*</sup> Limited only maximum junction temperature

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#### **Thermal Characteristics**

Characteristic	Symbol	Rating	Unit
Thermal resistance, junction to case	$R_{th(j-c)}$	Max. 1.13	°C/W
Thermal resistance, junction to ambient	$R_{th(j-a)}$	Max. 50	C/ W

#### Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Drain-source breakdown voltage	BV <sub>DSS</sub>	I <sub>D</sub> =250uA, V <sub>GS</sub> =0	650	-	-	٧
Gate threshold voltage	$V_{GS(th)}$	I <sub>D</sub> =250uA, V <sub>DS</sub> =V <sub>GS</sub>	3	-	5	V
Drain-source cut-off current		V <sub>DS</sub> =650V, V <sub>GS</sub> =0V	-	-	1	uA
Drain-source cut-on current	I <sub>DSS</sub>	V <sub>DS</sub> =650V, T <sub>c</sub> =150°C	-	-	100	uA
Gate leakage current	I <sub>GSS</sub>	$V_{DS}$ =0V, $V_{GS}$ =±30V	-	-	±100	nA
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =3.5A	-	1.1	1.4	Ω
Forward transfer conductance (Note 3)	g <sub>fs</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =3.5A	-	8.7	-	S
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0MHz	-	1385	-	pF
Output capacitance	C <sub>oss</sub>		-	102	-	
Reverse transfer capacitance	C <sub>rss</sub>		-	5.5	-	
Turn-on delay time (Note 3,4)	t <sub>d(on)</sub>	$V_{DS}$ =325V, $I_{D}$ =7A, $R_{G}$ =25 $\Omega$	-	60	-	
Rise time (Note 3,4)	t <sub>r</sub>		-	32	-	
Turn-off delay time (Note 3,4)	t <sub>d(off)</sub>		-	113	-	ns
Fall time (Note 3,4)	t <sub>f</sub>		_	22	-	
Total gate charge (Note 3,4)	$Q_g$		-	18	23	
Gate-source charge (Note 3,4)	$Q_{gs}$	$V_{DS}$ =520V, $V_{GS}$ =10V, $I_{D}$ =7A	-	7	-	nC
Gate-drain charge (Note 3,4)	$Q_{gd}$		-	3	-	

#### Source-Drain Diode Ratings and Characteristics (T<sub>c</sub>=25°C unless otherwise noted)

Total of Plant Prode Mathings and Orlandstor lottes (16 25 5 amoss stills wise noted)						
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Source current (DC)	Is	Integral reverse diode	-	-	7	Α
Source current (Pulsed)	I <sub>SM</sub>	in the MOSFET	-	-	28	Α
Forward voltage	$V_{SD}$	$V_{GS}=0V$ , $I_{SD}=7A$	-	-	1.4	V
Reverse recovery time (Note 3,4)	t <sub>rr</sub>	I <sub>SD</sub> =7A, V <sub>GS</sub> =0V dI <sub>F</sub> /dt=100A/us	-	410	-	ns
Reverse recovery charge (Note 3,4)	Q <sub>rr</sub>		-	1.7	-	uC

- 1. Repeated rating: Pulse width limited by safe operating area
- 2. L=3.5mH,  $I_{AS}$ =7A,  $V_{DD}$ =50V,  $R_G$ =25 $\Omega$ , Starting  $T_J$ =25°C 3. Pulse test: Pulse width $\leq$ 300us, Duty cycle $\leq$ 2%
- 4. Essentially independent of operating temperature typical characteristics

#### **Typical Electrical Characteristics Curves**

Fig. 1 Typical Output Characteristics

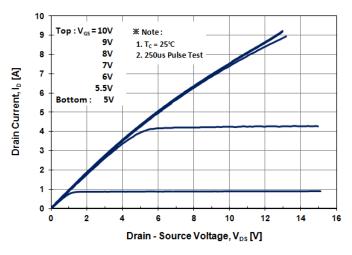


Fig. 2 Typical Output Characteristics

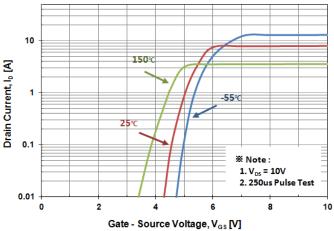


Fig.3 On-Resistance Variation with Drain Current and Gate Voltage

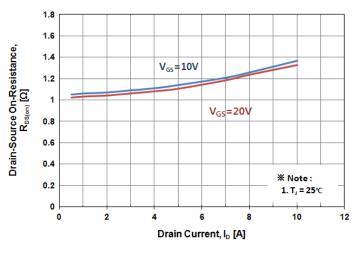


Fig. 4 Body Diode Forward Voltage Variation with Source Current

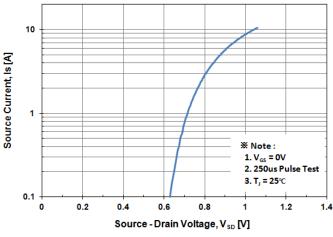


Fig. 5 Typical Capacitance Characteristics

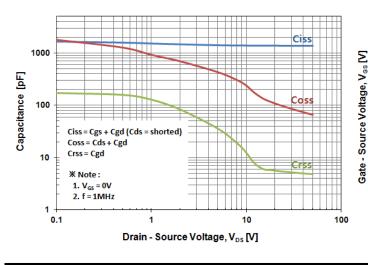
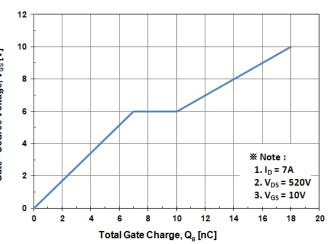


Fig. 6 Typical Total Gate Charge Characteristics



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Fig. 7 Breakdown Voltage Variation vs. Temperature

Fig. 8 On-Resistance Variation vs. Temperature

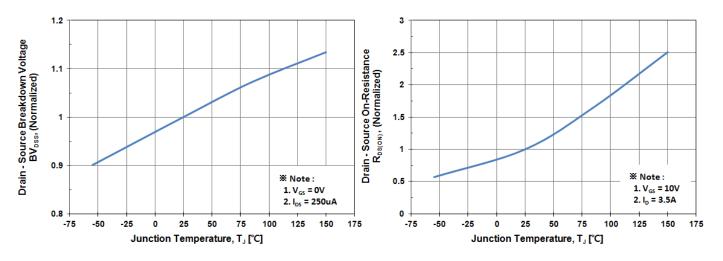


Fig. 9 Maximum Drain Current vs. Case Temperature

Fig. 10 Maximum Safe Operating Area

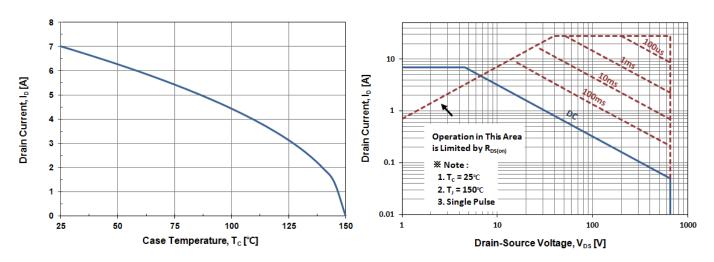
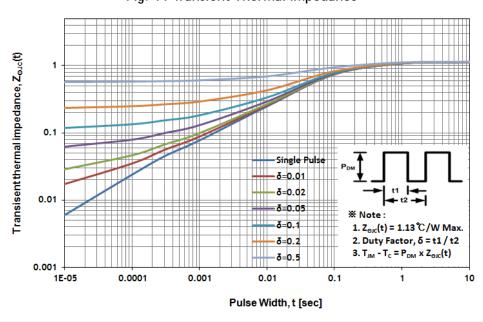
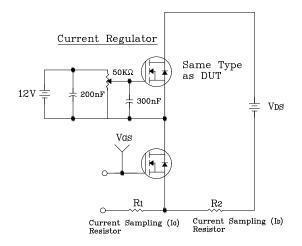


Fig. 11 Transient Thermal Impedance



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Fig. 12 Gate Charge Test Circuit & Waveform



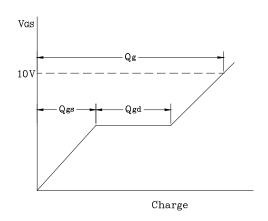
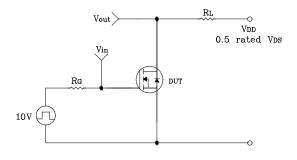


Fig. 13 Resistive Switching Test Circuit & Waveform



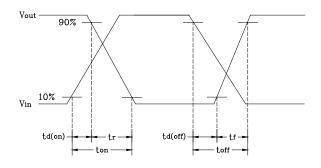
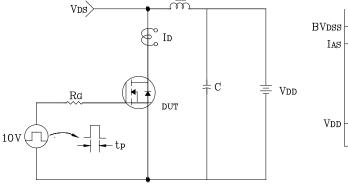


Fig. 14 E<sub>AS</sub> Test Circuit & Waveform



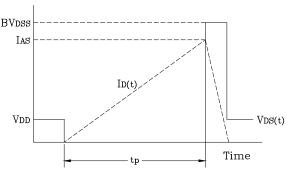
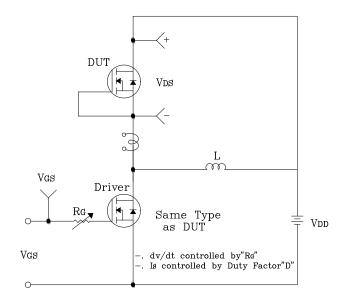
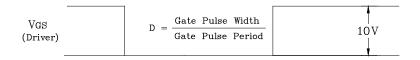
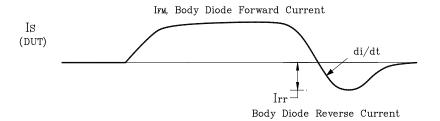
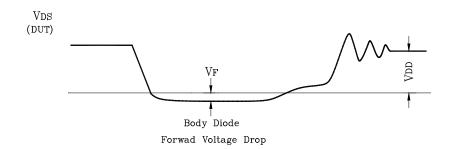


Fig. 15 Diode Reverse Recovery Time Test Circuit & Waveform

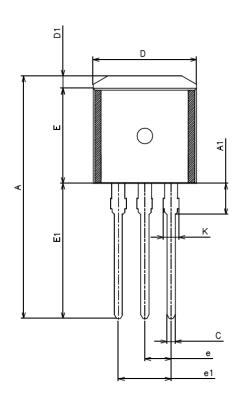


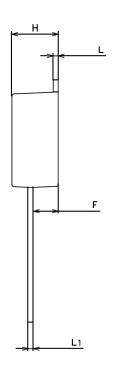


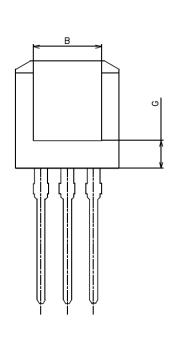




## Package Outline Dimensions







SYMBOL	N	NOTE		
SIMBOL	MINIMUM	NOMINAL	MAXIMUM	INOIL
Α	22.98	23.48	23.98	
Α1	2.80	3.00	3.20	
В	6.40	6.60	6.80	
С	0.60	0.80	1.00	
D	9.80	10.00	10.20	
D1	1.00	1.20	1.40	
E	9.05	9.20	9.35	
E1	12.68	13.08	13.48	
е	2.34	2.54	2.74	
e1	4.88	5.08	5.28	
F	2.20	2.40	2.60	
G	2.50	2.70	2.90	
Н	4.35	4.50	4.65	
K	1.42	1.52	1.62	
L	0.40	0.50	0.60	
L1	0.40	0.50	0.60	

SUN076512

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